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FACSIMILE COVER SHEET

November 3, 2005

Receiver: Examiner Julio J. Maldonado
(USPTO Central Fax)

FAX #: (571) 273-8300

Sender: Denise S. Bergin
Our Ref. No.: NOVLP074

Application No: 09/998,993

Re: 1. Amendment Transmittal
2. Response F

Pages Including Cover Sheet(s): 11

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Turner, et al.

Attorney Docket No.:
NOVLP074/NVLS-000414

Application No.: 09/998,993

Examiner: Maldonado, Julio J.

Filed: November 15, 2001

Group: 2823

Title: PHOSPHOROUS-DOPED SILICON
DIOXIDE PROCESS TO CUSTOMIZE
CONTACT ETCH PROFILES

CERTIFICATE OF FACSIMILE TRANSMISSION

I hereby certify that this correspondence is being transmitted by
facsimile to fax number 571-273-8300 to the U.S. Patent and
Trademark Office on November 3, 2005.

Signed: _____

Tara Hayden

RESPONSE F

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

This paper is submitted in response to the Office Action dated May 3, 2005 in the above-identified application. Please amend the application as follows:

Amendments to the Claims begin on page 2 of this paper.

Remarks/Arguments begin on page 8 of this paper.